NSN 5962-01-450-5691

Memory Microcircuit - Page 1 of 1



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Features Provided:
Burn in, mil-std-883, class b and low power and high performance and 3-state output
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Memory Device Type:
Eeprom
Special Features:
Access speed 120.0 nanoseconds
Terminal Type And Quantity:
32 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0